

Vishay Semiconductors

RF PIN Diodes - Single in MiniMELF SOD-80

Features

ISHA

- Wide frequency range 10 MHz to 1 GHz
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Applications

Current controlled HF resistance in adjustable attenuators



Mechanical Data

Case: MiniMELF SOD-80 Weight: approx. 31 mg Cathode band color: Black Packaging codes/options: GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Type differentiation	Ordering code	Type Marking	Remarks
BA679	$Z_R > 5 k\Omega$	BA679-GS18 or BA679-GS08	-	Tape and Reel
BA679S	$Z_R > 9 k\Omega$	BA679S-GS18 or BA679S-GS08	-	Tape and Reel

ROHS COMPLIANT

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Reverse voltage		V _R	30	V	
Forward continuous current		١ _F	50	mA	

Thermal Characteristics

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Thermal resistance junction to ambient air	on PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W	
Junction temperature		Тj	125	°C	
Storage temperature range		T _{stg}	- 55 to + 150	°C	

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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 20 mA		V _F			1000	mV
Reverse current	V _R = 30 V		I _R			50	nA
Diode capacitance	f = 100 MHz, V _R = 0		CD			0.5	pF
Differential forward resistance	f = 100 MHz, I _F = 1.5 mA		r _f			50	Ω
Reverse impedance	f = 100 MHz, V _R = 0	BA679	z _r	5			kΩ
		BA679S	z _r	9			kΩ
Minority carrier lifetime	l _F = 10 mA, l _R = 10 mA		τ		4		μs

Typical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

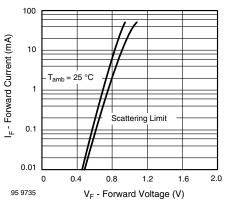


Figure 1. Forward Current vs. Forward Voltage

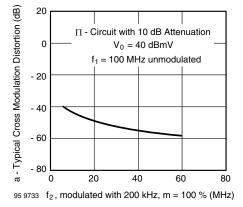


Figure 3. Typ. Cross Modulation Distortion vs. Frequency f₂

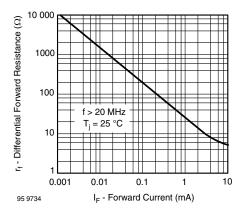


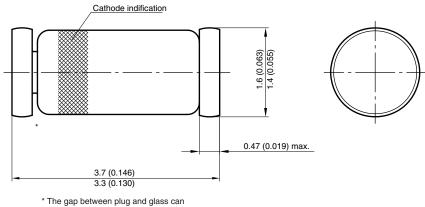
Figure 2. Differential Forward Resistance vs. Forward Current



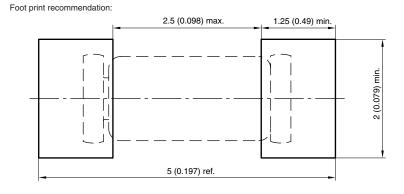
BA679, BA679S

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Package Dimensions in millimeters (inches): MiniMELF SOD-80



be either on cathode or anode side



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